



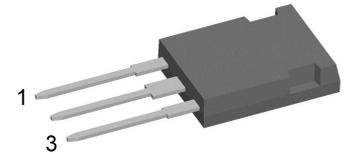
Schottky Diode

$V_{RRM} = 60\text{ V}$
 $I_{FAV} = 2 \times 40\text{ A}$
 $V_F = 0,51\text{ V}$

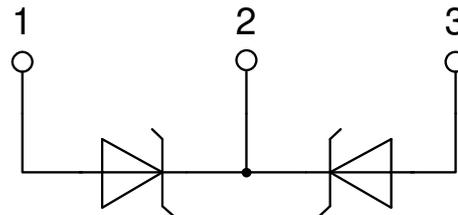
High Performance Schottky Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DSSK80-006BR



Backside: isolated



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: ISOPLUS247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

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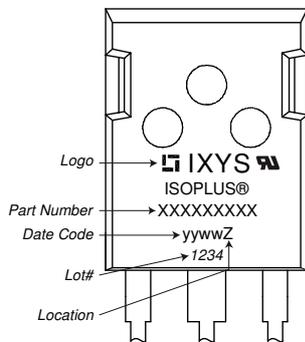


| Schottky | | | | Ratings | | | |
|------------|--|--|-------------|------------------------------|------|------|------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 60 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 60 | V |
| I_R | reverse current, drain current | $V_R = 60\text{ V}$ | | $T_{VJ} = 25^\circ\text{C}$ | | 2 | mA |
| | | $V_R = 60\text{ V}$ | | $T_{VJ} = 100^\circ\text{C}$ | | 200 | mA |
| V_F | forward voltage drop | $I_F = 40\text{ A}$ | | $T_{VJ} = 25^\circ\text{C}$ | | 0,55 | V |
| | | $I_F = 80\text{ A}$ | | | | 0,75 | V |
| | | $I_F = 40\text{ A}$ | | $T_{VJ} = 125^\circ\text{C}$ | | 0,51 | V |
| | | $I_F = 80\text{ A}$ | | | | 0,74 | V |
| I_{FAV} | average forward current | $T_C = 115^\circ\text{C}$ | rectangular | $T_{VJ} = 150^\circ\text{C}$ | | 40 | A |
| | | | d = 0.5 | | | | |
| V_{F0} | threshold voltage | } for power loss calculation only | | | | 0,27 | V |
| r_F | slope resistance | | | | | 5,7 | mΩ |
| R_{thJC} | thermal resistance junction to case | | | | | 0,8 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | | 0,25 | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 190 | W |
| I_{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine; $V_R = 0\text{ V}$ | | $T_{VJ} = 45^\circ\text{C}$ | | 700 | A |
| C_J | junction capacitance | $V_R = 12\text{ V}$ f = 1 MHz | | $T_{VJ} = 25^\circ\text{C}$ | | 1,34 | nF |



| Package ISOPLUS247 | | Ratings | | | | |
|--------------------|--|-------------------------------------|--------------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal ¹⁾ | | | 70 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 150 | °C |
| T_{op} | operation temperature | | -55 | | 125 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| F_C | mounting force with clip | | 20 | | 120 | N |
| $d_{Spp/APP}$ | creepage distance on surface / striking distance through air | terminal to terminal | 2,7 | | | mm |
| $d_{Spb/APb}$ | | terminal to backside | 4,1 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second t = 1 minute | 3600 3000 | | | V |
| | | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | | | | V |

Product Marking



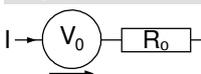
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSSK80-006BR | DSSK80-006BR | Tube | 30 | 499552 |

| Similar Part | Package | Voltage class |
|--------------|--------------|---------------|
| DSSK80-006B | TO-247AD (3) | 60 |

Equivalent Circuits for Simulation

** on die level*

$T_{VJ} = 150^{\circ}C$

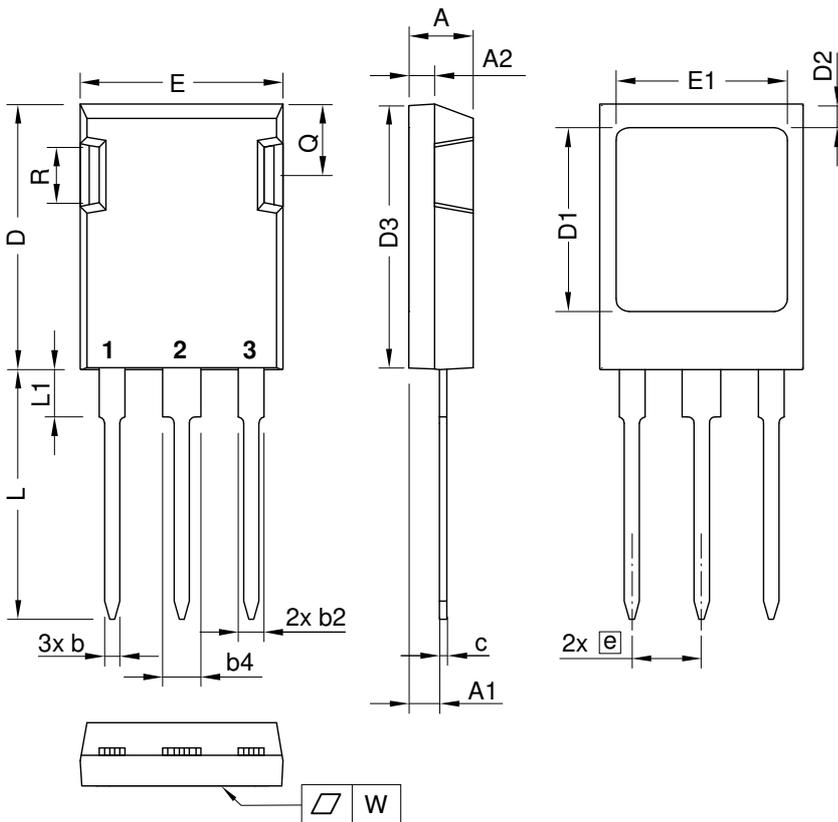


Schottky

| | | | |
|--------------|--------------------|------|----|
| $V_{0 \max}$ | threshold voltage | 0,27 | V |
| $R_{0 \max}$ | slope resistance * | 3,1 | mΩ |



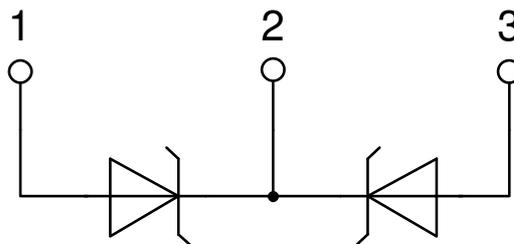
Outlines ISOPLUS247



| Dim. | Millimeter | | Inches | |
|------|------------|-------|-----------|-------|
| | min | max | min | max |
| A | 4.83 | 5.21 | 0.190 | 0.205 |
| A1 | 2.29 | 2.54 | 0.090 | 0.100 |
| A2 | 1.91 | 2.16 | 0.075 | 0.085 |
| b | 1.14 | 1.40 | 0.045 | 0.055 |
| b2 | 1.91 | 2.20 | 0.075 | 0.087 |
| b4 | 2.92 | 3.24 | 0.115 | 0.128 |
| c | 0.61 | 0.83 | 0.024 | 0.033 |
| D | 20.80 | 21.34 | 0.819 | 0.840 |
| D1 | 15.75 | 16.26 | 0.620 | 0.640 |
| D2 | 1.65 | 2.15 | 0.065 | 0.085 |
| D3 | 20.30 | 20.70 | 0.799 | 0.815 |
| E | 15.75 | 16.13 | 0.620 | 0.635 |
| E1 | 13.21 | 13.72 | 0.520 | 0.540 |
| e | 5.45 BSC | | 0.215 BSC | |
| L | 19.81 | 20.60 | 0.780 | 0.811 |
| L1 | 3.81 | 4.38 | 0.150 | 0.172 |
| Q | 5.59 | 6.20 | 0.220 | 0.244 |
| R | 4.25 | 5.50 | 0.167 | 0.217 |
| W | - | 0.10 | - | 0.004 |

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite
The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side

Die Gehäuseabmessungen entsprechen dem Typ TO-247 AD gemäß JEDEC außer Schraubloch und L_{max} .
This drawing will meet all dimensions requirement of JEDEC outline TO-247 AD except screw hole and except L_{max} .



Schottky

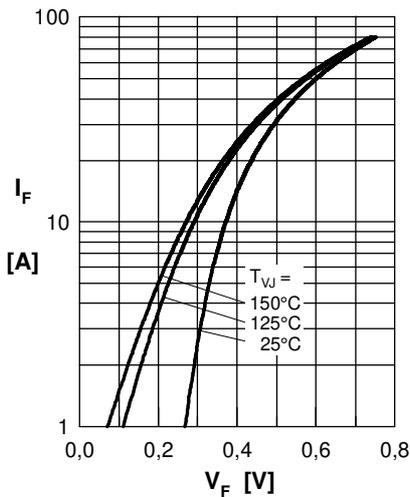


Fig. 1 Max. forward voltage drop characteristics

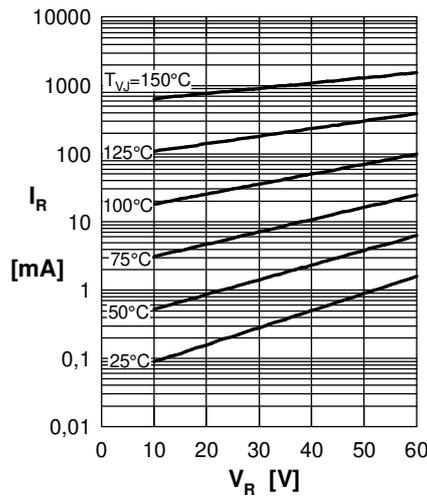


Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

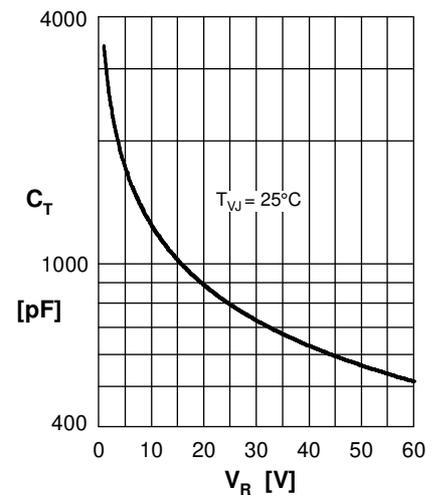


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

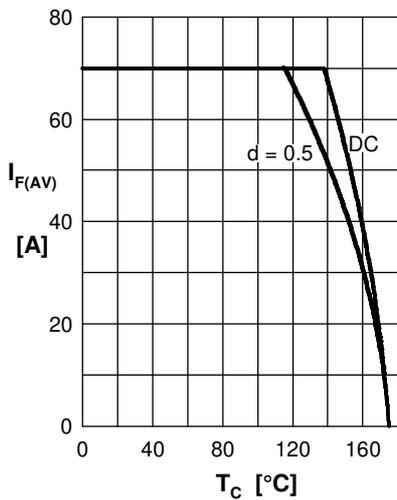


Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

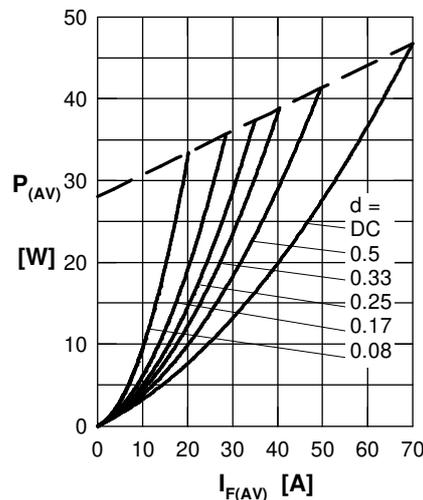


Fig. 5 Forward power loss characteristics

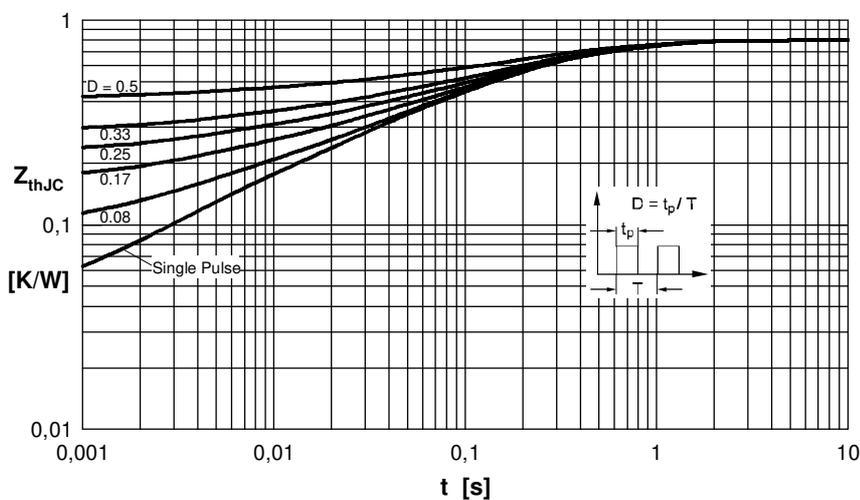


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode